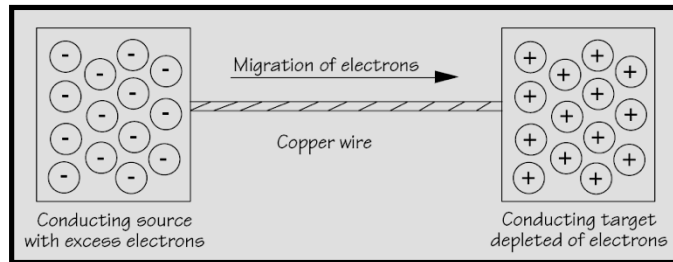


Basic Concepts of Electricity

- Voltage E Ohm's Law
- Current I
- Resistance R $E = I R$



1

Electric Fields

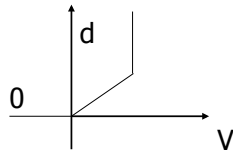
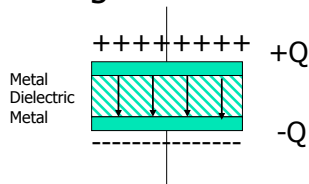
- An electric field applies a force to a charge
 - Force on positive charge is in direction of electric field, negative is opposite
- Charges move if they are mobile
- An electric field is produced by charges (positive and negative charges)
- Electric fields can be produced by time varying magnetic fields (generator, antenna radiation)

2

Voltage Difference

- Voltage difference is the difference in potential energy in an electric field
- $E = V/d$
- As you move closer to a positive charge the voltage increases

Capacitor
(electric field
constant between
parallel plates)



3

Current

- An electric current is produced by the flow of electric charges
- Current = rate of charge movement
= amount of charge crossing a surface per unit time
- In conductors, current flow is due to electrons
- Conventional current is defined by the direction positive charges will flow
- Direction of electron flow is opposite to direction of conventional current

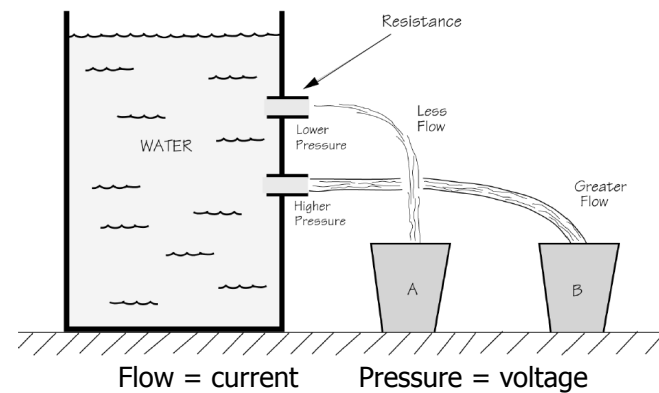
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Resistance

- In materials electrons accelerate in an electric field
- Electrons lose energy when they hit atoms - lost energy appears as heat and light
- The result is that electrons drift with constant velocity (superimposed on random thermal motion)
- Resistance is the ratio Voltage/current
 $R = V/I$

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Voltage, Current, and Resistance



6

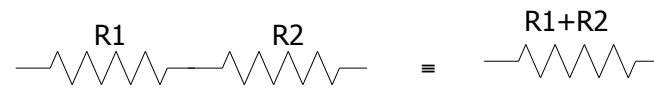
Material Conductivity

- Conductors - negligible resistance
- Insulators - extremely large resistance
- Semiconductors - some resistance
- Resistors - are devices designed to have constant resistance across a range of voltages

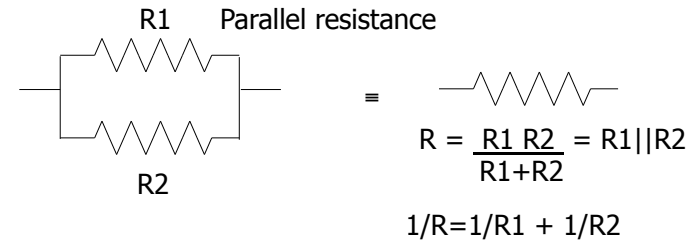
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Resistor Combination

Series resistance

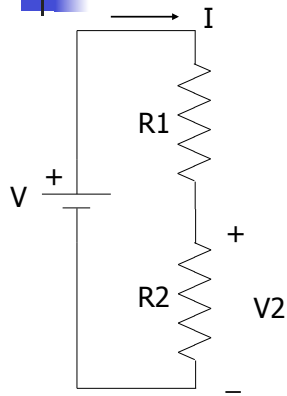


Parallel resistance



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Voltage Divider



$$V_2 = \frac{V R_2}{R_1 + R_2}$$

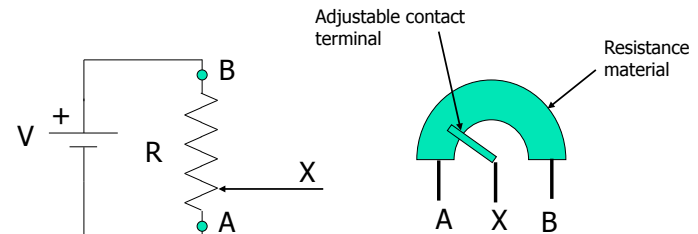
Solution:

Goal: Find V_2 given V

- Find V_2 in terms of I
- Current through R_2 in terms of I
- Voltage across R_1
- Find voltage across R_1 and R_2 using two different methods

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Potentiometer (Variable Resistor)



$$V_X = V * \text{Distance AX} / \text{Distance AB}$$

(linear potentiometer)

A trimpot is a small variable resistor mounted on a printed circuit board that can be adjusted by a small screwdriver to make semi-permanent adjustments to a circuit

10



Input Transducers

- These are devices that produce electric signals in accordance with changes in some physical effect e.g. convert temperature, light level to a voltage level or resistance
- e.g. microphones, strain gauge, photo-detectors, ion-selective membranes, thermistors
- Sometimes the definition of transducer is that of a device that converts non-electrical energy to electrical energy

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Output Transducers

- Devices which convert an electrical quantity into some other physical quantity or effect e.g. relay, loudspeaker, solenoid

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Light Dependent Resistors (LDRs)

- Devices whose resistance changes (usually decreases) with light striking it
- (also called photocells, photoconductors)
- Light striking a semiconducting material can provide sufficient energy to cause electrons to break away from atoms.
- Free electrons and holes can be created which causes resistance to be reduced

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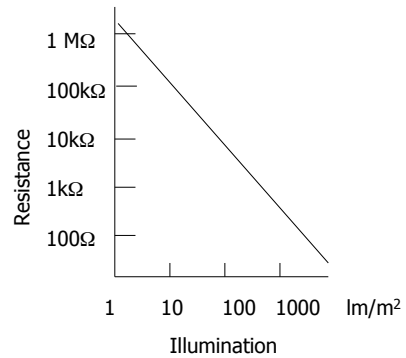
LDRs

- Typical materials used are Cadmium Sulphide (CdS), Cadmium Selenide (CdSe), Lead Sulphide
- With no illumination, resistance can be greater than 1 M Ω (dark resistance).
- Resistance varies inversely proportional to light intensity.
- Reduces down to 10-100s ohms
- 100ms/10ms response time

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CdS LDR
Top view



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- LDRs have a low energy gap
- Operate over a wide wavelengths (some, into infrared)
- Indium antimonide is good for IR. When cooled is very sensitive, used for thermal scanning of earth's surface

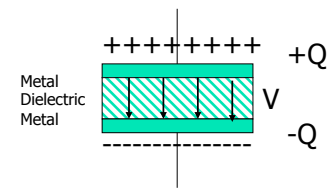
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Capacitors

- A component constructed from two conductors separated by an insulating material (dielectric) that stores electric charge (+Q, -Q)
- As a consequence there is a voltage difference across the capacitor, V
- Capacitance = $C = Q/V$
- The dielectric material operates to reduce the electric field between the conductors and so allow more charge to be stored for a given voltage

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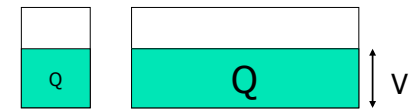
Capacitors



$$C = Q/V$$

$$(Q = CV)$$

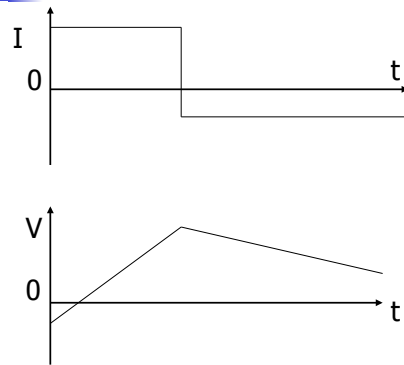
Bucket analogy



A small bucket (capacitor, C) holds less charge (Q) for given level (voltage V) than a large bucket

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Charging a Capacitor



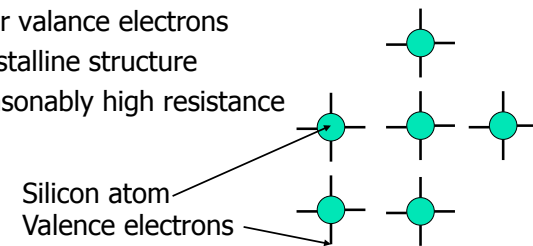
The bucket analogy can be used to describe capacitor charging

When current flows in at a constant rate the voltage increases linearly and vice versa for current flowing out

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Semiconductors

- Silicon is used as an example (other semiconductors include Germanium, Gallium Arsenide, Gallium phosphide, indium arsenide, indium phosphide)
- Pure silicon (intrinsic semiconductor)
 - Four valence electrons
 - Crystalline structure
 - Reasonably high resistance



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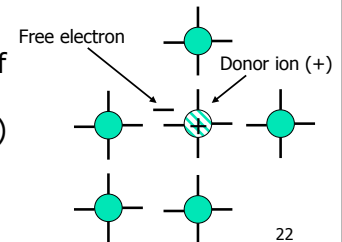
Electrons and holes

- Due to thermal energy some electrons in the valance shell become free
- Create:
 - One free electron +
 - One hole in the valance band that can be filled by electrons from the valance band in an adjacent silicon atom
- Current in silicon can flow due to both movement of electrons and holes

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n-type silicon

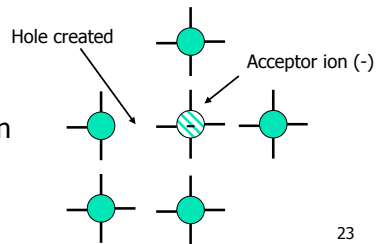
- Add donor impurities (e.g. Phosphorus, arsenic, indium) with 5 electrons in the valance band
- As only four electrons can bond with neighbouring silicon atoms one free electron is left
- Increases concentration of free electrons
- Reduces concentration of holes (due to increased chance of recombination)
- Resistance reduced



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p-type silicon

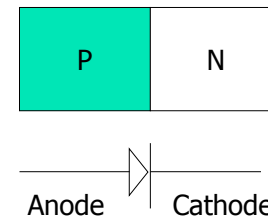
- p-type silicon is created by adding acceptor impurities which have three valence electrons (e.g. boron)
- This leaves an unbound valence electron in an adjacent silicon atom creating a hole
- Increases concentration of holes
- Reduces concentration of free electrons
- P-type silicon has lower resistance than pure silicon



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Diodes

- If a piece of n-type silicon and p-type silicon are joined directly together a diode (di - electrode) device is created



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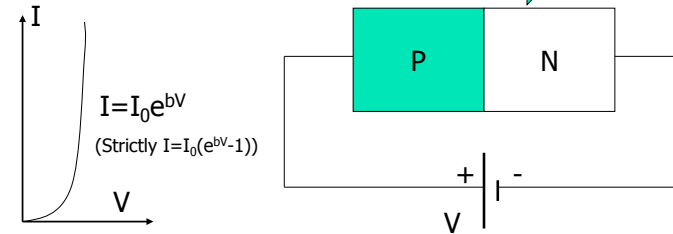
Macro-behaviour

- A diode is a device that allows current flow easily in one direction easily and allows hardly any current flow in the opposite direction

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Forward bias

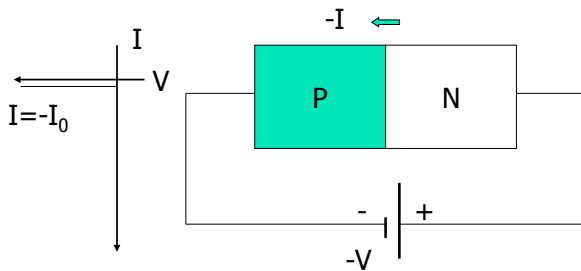
- Current flows easily if the P region is positive with respect to the N region



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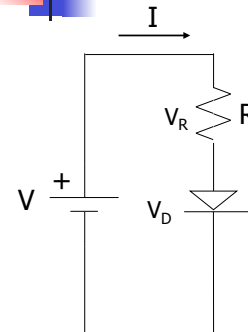
Reverse bias

- Current hardly flows if the P region is negative with respect to the N region



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Diode and resistor circuit



Currents and voltages determined by:
(work backwards to find V_D)

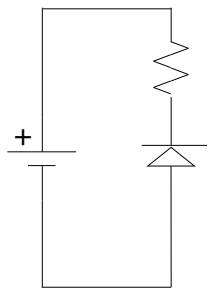
- V_D related to I by diode equation
- Current in resistor and diode equal
- $V_R = IR$
- voltage across diode and voltage resistor add up to voltage source V

Short cut rule of thumb, V_D is approx 0.6-0.7 volts and $V_R \approx V - 0.6$
For LEDs V_D is about 1.8 - 4.0 V, depending on colour

Forward biased diode

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Diode and resistor circuit



Reverse biased diode

Assume no reverse-bias current flows (ideal case)

Therefore no voltage occurs across the resistor

Therefore the full supply voltage appears across the diode

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LEDs

- Light emitting diode
- When an electron moves down from the conduction band to the valence band it loses energy
- In silicon and germanium the energy-momentum relationships mean that this energy is lost heat
- In gallium arsenide it produces a photon

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LEDs

- The light intensity is proportional to current
- Pure gallium arsenide produces infrared light
- GaAsP produces red or yellow light
- GaP produces red or green

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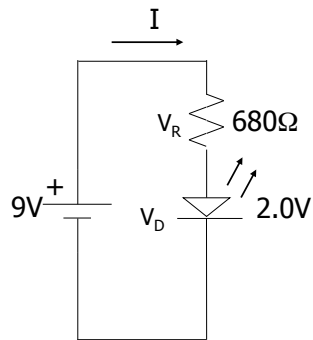


Circuit design using LEDs

- LEDs behave just like normal diodes except that the forward bias voltages are greater (typically 1.8 - 4.0 V)
- A typical forward bias current of 10-20 mA is used.

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Example



$$I = \frac{9 - 2.0}{680} \\ = 10.29 \text{ mA}$$